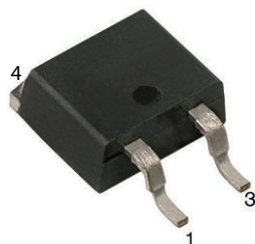
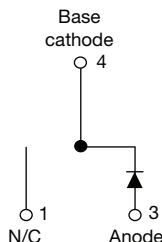


1200 V Gen 3 Power SiC Merged PIN Schottky Diode, 5 A


D²PAK 2L (TO-263AB 2L)


FEATURES

- Majority carrier diode using Schottky technology on SiC wide band gap material
- High CTI molding compound provides excellent electrical insulation at relevant working voltages
- Improved V_F and efficiency by thin wafer technology
- Positive V_F temperature coefficient for easy paralleling
- Virtually no recovery tail and no switching losses
- Temperature invariant switching behavior
- 175 °C maximum operating junction temperature
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C
- MPS structure for high ruggedness to forward current surge events
- Meets JESD 201 class 1A whisker test
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912


RoHS
COMPLIANT
HALOGEN
FREE

LINKS TO ADDITIONAL RESOURCES



PRIMARY CHARACTERISTICS	
I_F	5 A
V_R	1200 V
V_F at I_F at 25 °C, typ.	1.35 V
T_J max.	175 °C
I_R at V_R at 175 °C	3 μ A
Q_C ($V_R = 800$ V)	28 nC
Package	D ² PAK 2L (TO-263AB 2L)
Circuit configuration	Single

DESCRIPTION / APPLICATIONS

Wide band gap SiC based 1200 V Schottky diode, designed for high performance and ruggedness.

Optimum choice for high speed hard switching and efficient operation over a wide temperature range, it is also recommended for all applications suffering from Silicon ultrafast recovery behavior.

Typical applications include AC/DC PFC and DC/DC ultra high frequency output rectification in FBPS and LLC converters.

MECHANICAL DATA

Case: D²PAK 2L (TO-263AB 2L)

Molding compound meets UL 94 V-0 flammability rating
Base P/N-M3 - halogen-free, RoHS-compliant

Terminals: matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

MAXIMUM RATINGS ($T_A = 25$ °C unless otherwise specified)				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Peak repetitive reverse voltage	V_{RRM}		1200	V
Continuous forward current	$I_F^{(1)}$	$T_C = 152$ °C (DC)	5	A
	$I_F^{(2)}$	$T_C = 157$ °C (DC)		
DC blocking voltage	V_{DC}		1200	V
Repetitive peak forward current	I_{FRM}	$T_C = 25$ °C, $f = 50$ Hz, square wave, DC = 25 %	27	A
Non-repetitive peak forward surge current	I_{FSM}	$T_C = 25$ °C, $t_p = 10$ ms, half sine wave	42	
		$T_C = 110$ °C, $t_p = 10$ ms, half sine wave	39	
Power dissipation	$P_{tot}^{(1)}$	$T_C = 25$ °C	60	W
		$T_C = 110$ °C	26	
	$P_{tot}^{(2)}$	$T_C = 25$ °C	79	W
		$T_C = 110$ °C	34	
I^2t value	$\int i^2 dt$	$T_C = 25$ °C	8.7	A ² s
		$T_C = 110$ °C	7.6	
Operating junction and storage temperatures	$T_J^{(3)}, T_{Stg}$		-55 to +175	°C

Notes

(1) Based on maximum R_{th}

(2) Based on typical R_{th}

(3) The heat generated must be less than the thermal conductivity from junction-to-ambient: $dP_D/dT_J < 1/R_{\theta JA}$

**ELECTRICAL SPECIFICATIONS** ($T_J = 25\text{ }^{\circ}\text{C}$ unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Forward voltage	V_F	$I_F = 5\text{ A}$	-	1.35	1.5	V
		$I_F = 5\text{ A}, T_J = 150\text{ }^{\circ}\text{C}$	-	1.73	2.0	
		$I_F = 5\text{ A}, T_J = 175\text{ }^{\circ}\text{C}$	-	1.85	-	
Reverse leakage current	I_R	$V_R = V_R\text{ rated}$	-	2.0	30	μA
		$V_R = V_R\text{ rated}, T_J = 150\text{ }^{\circ}\text{C}$	-	1.5	80	
		$V_R = V_R\text{ rated}, T_J = 175\text{ }^{\circ}\text{C}$	-	3.0	-	
Total capacitance	C	$V_R = 1\text{ V}, f = 1\text{ MHz}$	-	307	-	pF
		$V_R = 800\text{ V}, f = 1\text{ MHz}$	-	20	-	
Total capacitive charge	Q_C	$V_R = 800\text{ V}, f = 1\text{ MHz}$	-	28	-	nC

THERMAL - MECHANICAL SPECIFICATIONS ($T_A = 25\text{ }^{\circ}\text{C}$ unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Thermal resistance, junction to case	R_{thJC}		-	1.9	2.50	$^{\circ}\text{C/W}$
Marking device				3C05ET12S		

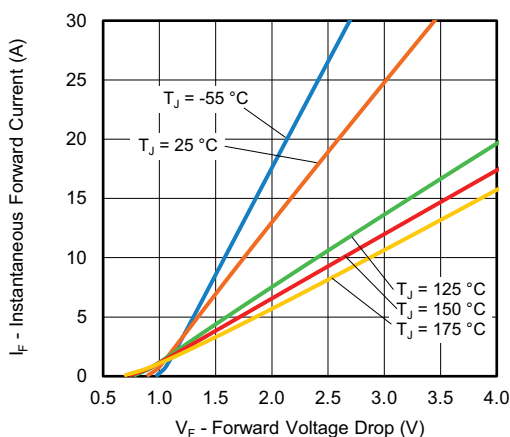


Fig. 1 - Typical Forward Voltage Drop Characteristics

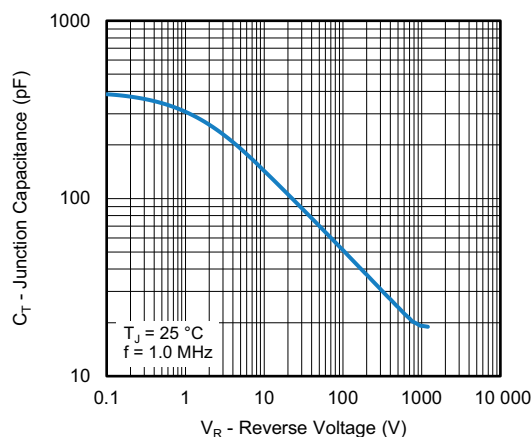


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

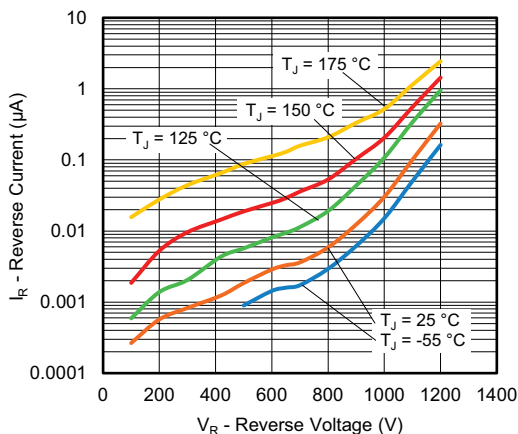


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

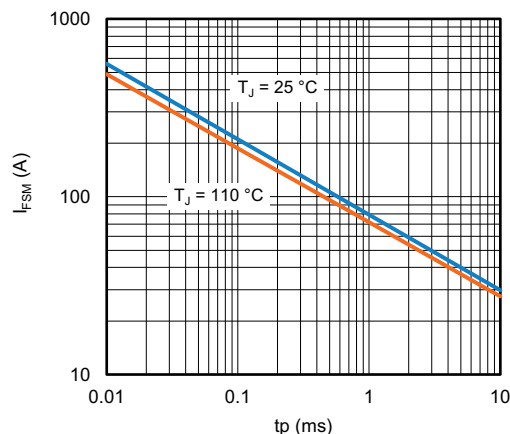


Fig. 4 - Non-Repetitive Peak Forward Surge Current vs. Pulse Duration (Square Wave)

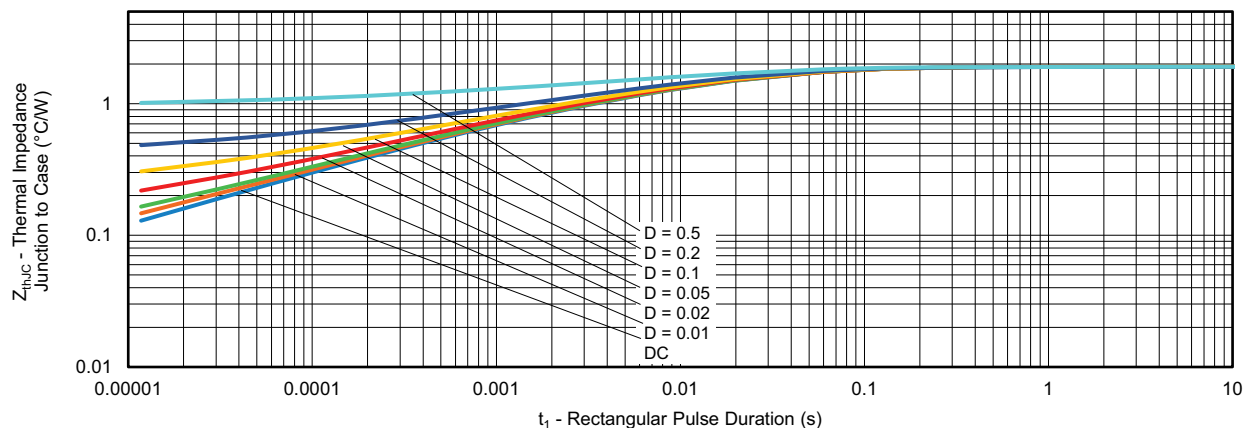


Fig. 5 - Typical Thermal Impedance Z_{thJC} Characteristics

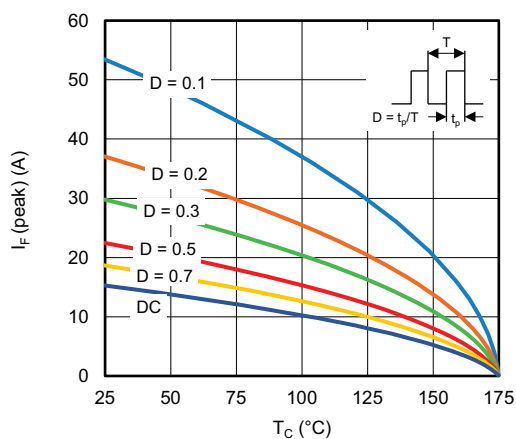


Fig. 6 - Peak Forward Current vs. Maximum Allowable Case Temperature

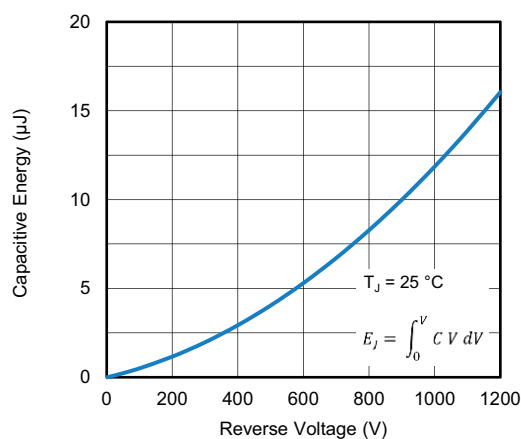


Fig. 8 - Typical Capacitive Energy vs. Reverse Voltage

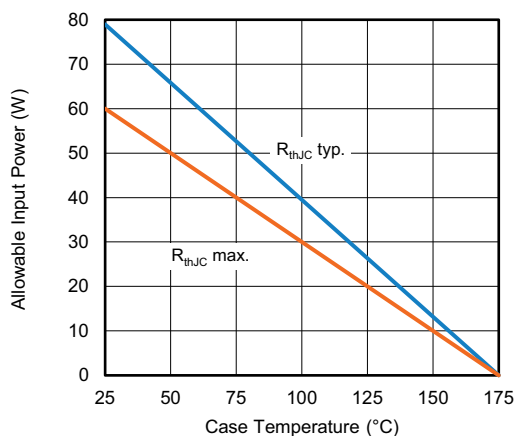


Fig. 7 - Forward Power Loss Characteristics

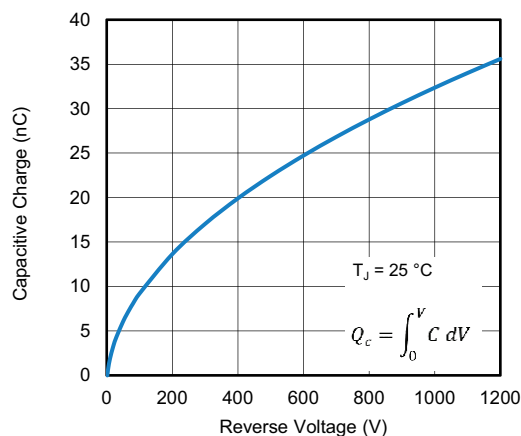


Fig. 9 - Typical Capacitive Charge vs. Reverse Voltage

**ORDERING INFORMATION TABLE**

Device code	VS-	3C	05	E	T	12	S	2	L	-M3
	1	2	3	4	5	6	7	8	9	10

- | | |
|-----------|--|
| 1 | - Vishay Semiconductors product |
| 2 | - 3C = SiC diode, generation 3 |
| 3 | - Current rating (05 = 5 A) |
| 4 | - E = single diode |
| 5 | - T = D ² PAK package |
| 6 | - Voltage rating: (12 = 1200 V) |
| 7 | - S = surface mountable |
| 8 | - 2 = true 2 pin D ² PAK |
| 9 | - L = tape and reel (left oriented) |
| 10 | - Environmental digit:
-M3 = halogen-free, RoHS-compliant, and termination lead (Pb)-free |

ORDERING INFORMATION

PREFERRED P/N	BASE QUANTITY	PACKAGING DESCRIPTION
VS-3C05ET12S2L-M3	800 per reel	13" diameter reel

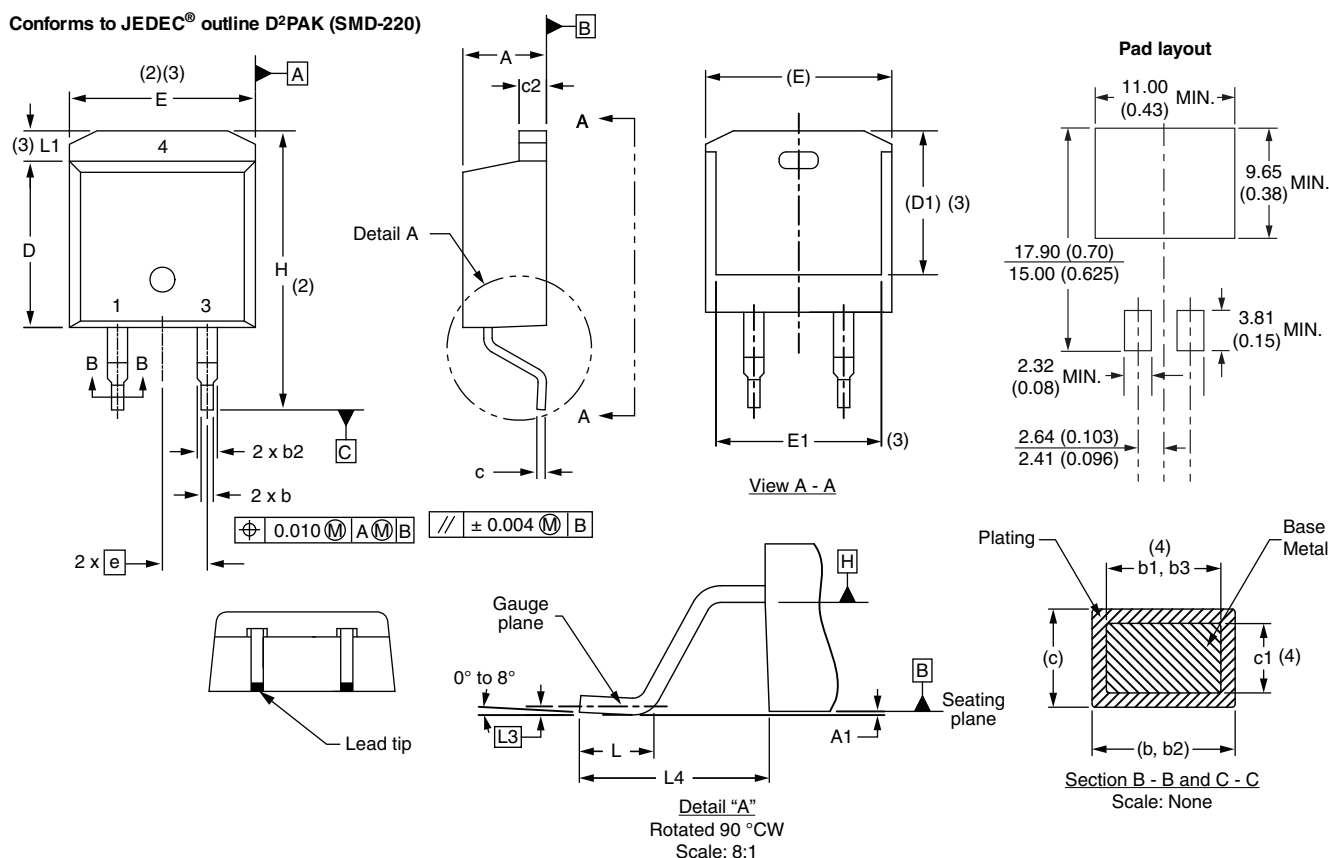
LINKS TO RELATED DOCUMENTS

Dimensions	www.vishay.com/doc?96683
Part marking information	www.vishay.com/doc?96693
Packaging information	www.vishay.com/doc?95032

D²PAK 2L (TO-263AB 2L)

DIMENSIONS in millimeters and inches

Conforms to JEDEC® outline D²PAK (SMD-220)



Notes

- (1) Dimensioning and tolerancing per ASME Y14.5 M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- (3) Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Datum A and B to be determined at datum plane H
- (6) Controlling dimension: inch
- (7) Outline conforms to JEDEC® outline TO-263AB



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